

MOS FIELD EFFECT TRANSISTOR 2SK3053

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SK3053 is N-Channel MOS Field Effect Transistor designed for high current switching applications in consumer instruments.

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3053	Isolated TO-220

FEATURES

- Low On-State Resistance $R_{DS(on)1} = 45 \text{ m}\Omega \text{ MAX.}$ (Vgs = 10 V, Ip = 13 A) $R_{DS(on)2} = 70 \text{ m}\Omega \text{ MAX.}$ (Vgs = 4.0 V, Ip = 13 A)
- Low Ciss : Ciss = 790 pF TYP.
- Built-in Gate Protection Diode
- Isolated TO-220 package

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

Drain to Source Voltage	Vdss	60	V
Gate to Source Voltage	VGSS(AC)	±20	V
Gate to Source Voltage	VGSS(DC)	+20, -10	V
Drain Current (DC)	D(DC)	±25	А
Drain Current (Pulse) Note1	D(pulse)	±75	А
Total Power Dissipation (Tc = 25°C)	Pτ	30	W
Total Power Dissipation (T _A = 25°C)	Рт	2.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	–55 to +150	°C
Single Avalanche Current Note2	las	12.5	Α
Single Avalanche Energy ^{Note2}	Eas	15.6	mJ

(Isolated TO-220)



Notes 1. PW \leq 10 μ s, Duty cycle \leq 1 %

2. Starting T_{ch} = 25 °C, V_{DD} = 30 V, R_G = 25 Ω , V_{GS} = 20 V \rightarrow 0 V

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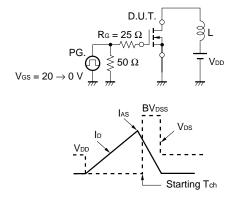
ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	RDS(on)1	Vgs = 10 V, Id = 13 A		28	45	mΩ
	RDS(on)2	Vgs = 4.0 V, Id = 13 A		46	70	mΩ
Gate to Source Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.0	1.6	2.0	V
Forward Transfer Admittance	y _{fs}	V _{DS} = 10 V, I _D = 13 A	8.0	16		S
Drain Leakage Current	IDSS	Vds = 60 V, Vgs = 0 V			10	μA
Gate to Source Leakage Current	lgss	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±10	μA
Input Capacitance	Ciss	V _{DS} = 10 V		790		pF
Output Capacitance	Coss	V _G s = 0 V		240		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		100		pF
Turn-on Delay Time	td(on)	ID = 13 A		20		ns
Rise Time	tr	Vgs = 10 V		200		ns
Turn-off Delay Time	td(off)	V _{DD} = 30 V		65		ns
Fall Time	tr	R _G = 10 Ω		95		ns
Total Gate Charge	QG	ID = 25 A		20		nC
Gate to Source Charge	QGS	V _{DD} = 48 V		3.0		nC
Gate to Drain Charge	Qgd	V _{GS} = 10 V		6.5		nC
Body Diode Forward Voltage	VF(S-D)	IF = 25 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 25 A, VGS = 0 V		40		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ <i>µ</i> s		45		nC

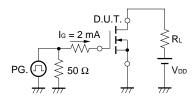
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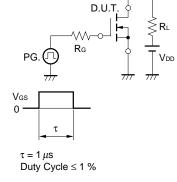
TEST CIRCUIT 1 AVALANCHE CAPABILITY

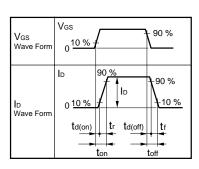
TEST CIRCUIT 2 SWITCHING TIME



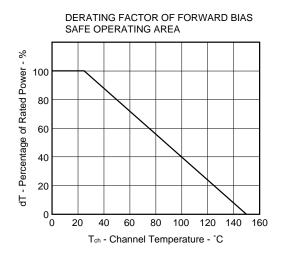
TEST CIRCUIT 3 GATE CHARGE

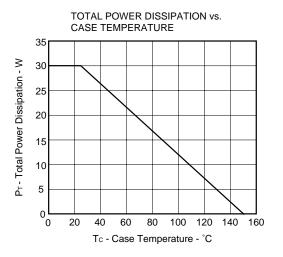




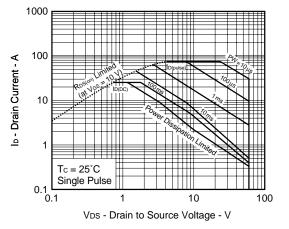


TYPICAL CHARACTERISTICS (TA = 25 °C)

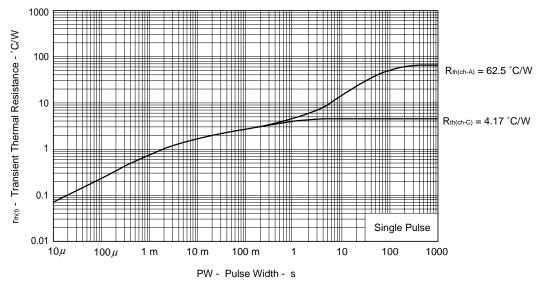




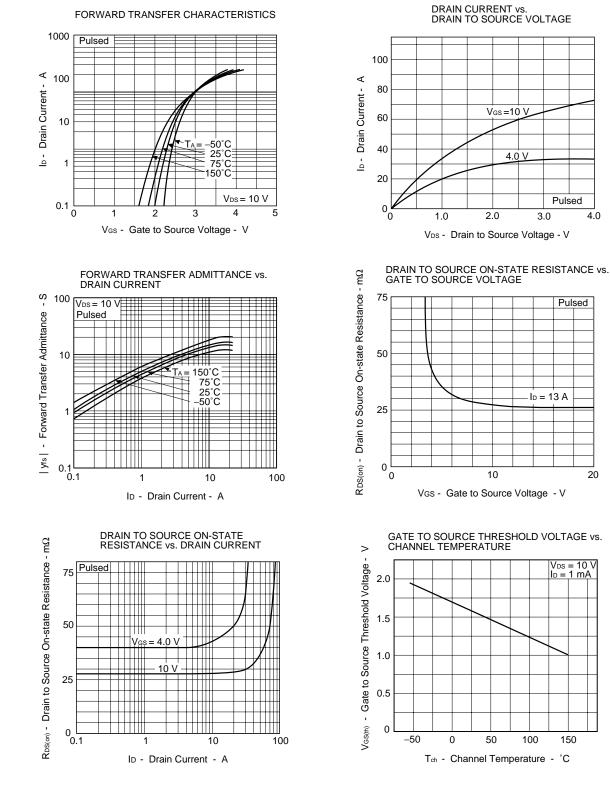
FORWARD BIAS SAFE OPERATING AREA



TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

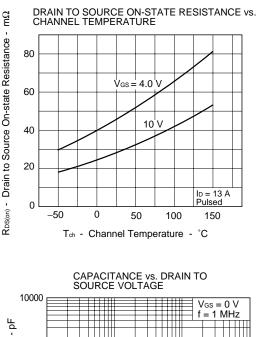


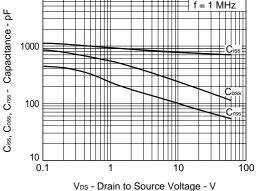
Data Sheet D12912EJ3V0DS

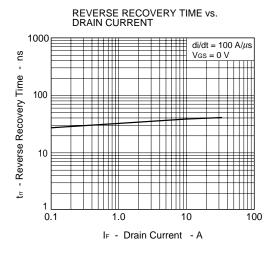


Data Sheet D12912EJ3V0DS

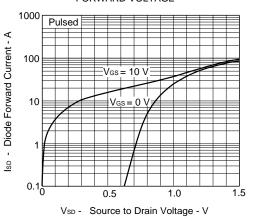
NEC



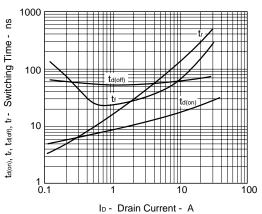




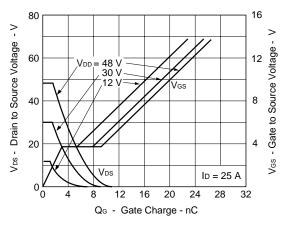
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



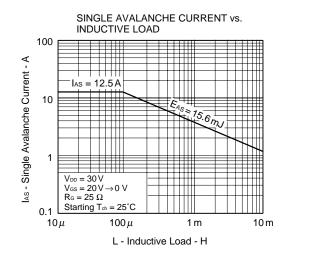
SWITCHING CHARACTERISTICS

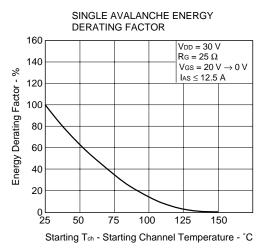






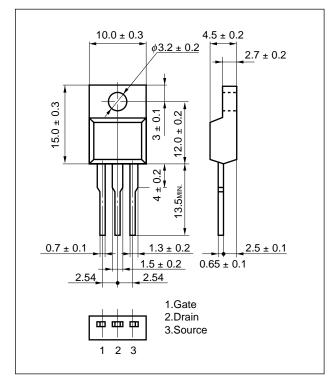
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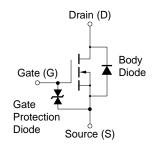


PACKAGE DRAWING

Isolated TO-220 (MP-45F)



EQUIVALENT CIRCUIT



Remark 1. This product is designed for consumer application and isn't suitable for automotive application.

2. The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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